MN4008B/MN4008BS

4-Bit Full Adder

■ Outline

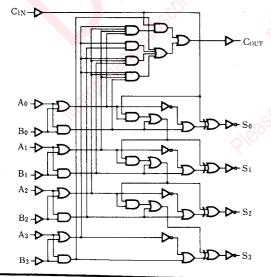
The MN4008B/S is a 4-bit parallel processing full adder equipped with a high speed parallel carry circuit. The sum of the four augend data inputs $(A_0 \sim A_3)$, the other four addend data inputs $(B_0 \sim B_3)$, and the binary input added to the carry input (C_{IN}) from the lower digit is obtainable in the binary code as the addend data outputs $(S_0 \sim S_3)$ and the carry output (C_{OUT}) to the upper digit.

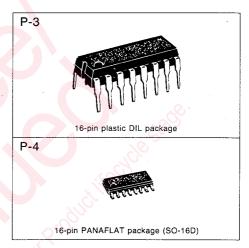
It enables easy constitution of a $4 \times n$ -bit adder circuit by cascade connection and adder-subtractor circuit supported by a simple external circuit.

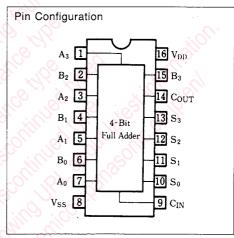
■ Truth Table

	Input	Output			
Cin	A	В	Соит	S	
L	L	L	L	L	
L	L	Н	L	Н	
L	Н	L	L	Н	
L	Н	Н	Н	L KC	
Н	L	L	L	H-S	
Н	L	Н	Н	L	
Н	Н	L	Н	C L	
H	Н	Н	Н	H	

Logic Diagram







■ Absolute Maximum Ratings (Ta=25°C)

Item		Symbol	Rating	Unit
Supply voltage		V _{DD}	-0.5~+18	V
Input voltage		V_{I}	$-0.5 \sim V_{DD} + 0.5*$	V
Output pin voltage		V _o	$-0.5 \sim V_{DD} + 0.5*$	V
Peak input · output pin current		$\pm I_{\mathfrak{l}}$	max. 10	mA
Power dissipation (per package)	$Ta = -40 \sim +60^{\circ}C$ $Ta = +60 \sim +80^{\circ}C$	P_{D}	max. 400 Decrease to 200mW at the rate of 8mW/°C	mW
Power dissipation (per output pin)		Po	max. 100	mW
Operating ambient temperature		T_{opr}	-40~+85	°C
Storage temperature		$T_{\rm stg}$	-65~+150	°C

^{*} $V_{DD}+0.5V$ should be lower than 18V.

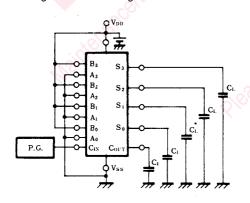
■ DC Characteristics (V_{SS}=0V)

■ DO Characteristics	(V SS	- U V)									
Item	V _{DD}	Symbol	Condition		Ta=-40°C		Ta=25°C		Ta=85°C		Unit
	(V)	Syllibol			min.	max.	min.	max.	min.	max.	Ome
	5					20	140	20		150	
Static supply current	10	I_{DD}	$V_1 = V_{SS}$ or	V_{DD} ,	/	40	7	40		300	μA
	15				_	80	P'_	80	_	600	
	5		V-V or	V-V or V		0.05	_	0.05	_	0.05	
Output voltage low level	10	Vol	$V_I = V_{SS}$ or V_{DD}		-	0.05		0.05	_	0.05	V
	15		$ I_{(i)} < 1\mu A$			0.05		0.05	_	0.05	
	5		V-V an	V	4.95	2-	4.95	_	4.95	_	
Output voltage high level			9.95	 C	V						
	15		$ I_0 < 1\mu A$		14.95	_	14.95	_	14.95		
	5			$V_0 = 0.5V$ or $4.5V$		01.5	6	— 1.5 — 1.5			
Input voltage low level	10	V_{IL}	$ I_0 < 1\mu A$	$V_0=1V$ or $9V$	197	3	R—	3		3	V
	15			$V_0 = 1.5V$ or $13.5V$	ر ـــاد	4	_	4		4	
	5		C	V ₀ =0.5V or 4.5V	3.5	- v	3.5	XQ2	3.5	<u> </u>	
Input voltage high level	10	VIH	$ I_0 < 1\mu A$	$V_0=1V$ or $9V$	7		7		7		V
	15		00	$V_0 = 1.5V$ or $13.5V$	11	50	11		11	_	
	5		$V_0 = 0.4V$,	V _I =0 or 5V	0.52	-	0.44	3	0.36		
Output current low level	10	IOL	$V_0 = 0.5V$,	$V_I=0$ or $10V$	1.3	\ - 0	1.1	0	0.9		mA
	15	CO.	$V_0 = 1.5V$, $V_1 = 0$ or $15V$ 3.6 — 3					_	2.4		
	5	P	$V_0=4.6V$, $V_1=0$ or $5V$ 0.52 — 0.44		0.44		0.36				
Output current high level	10	$-I_{OH}$	$V_0 = 9.5V$,	$V_i=0$ or $10V$	1.3		1.1		0.9	_	mA
	15		$V_0 = 13.5V$	$V_i=0$ or 15V	3.6	\ <u></u>	3		2.4		
Output current high level	5	$-I_{OH}$	$V_0 = 2.5V$,	$V_I=0$ or $5V$	1.7		1.4		1.1		mA
Input leakage current	15	±Ιι	$V_i=0$ or 15	5V	2,-	0.3		0.3	_	1	μΑ
	•			asi Mi							

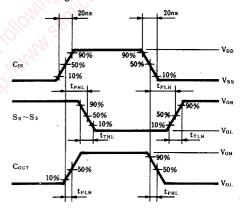
■ Switching Characteristics (Ta=25°C, V_{SS}=0V, C_L=50pF)

Item	$V_{DD}(V)$	Symbol	min.	typ.	max.	Unit
**	5			60	180	
Output rise time	10	. t _{TLH}	_	30	90	ns
	15			20	60	
	5		_	60	180	
Output fall time	10	t _{THL}		30	90	ns
	15			20	60	
Fransfer time	5			135	405	
	10	t _{PLH} .	_	55	165	ns
Sum in \rightarrow Sum out (L \rightarrow H)	15		 	40	120	
Γransfer time	5			150	450	>, •
	10	t _{PHL}	_	55	165	ns
Sum in \rightarrow Sum out (H \rightarrow L)	15	· .	_	40	120	
Γransfer time	5		_	100	300	
	10	t _{PLH}		45	135	ns
Sum in \rightarrow Cout (L \rightarrow H)	15		_	30	90	
Fransfer time	5		_	125	375	
	10	t _{PHL}	_	50	150	ns
Sum in→Cout (H→L)	15			35	105	
Fransfer time	5		<u> </u>	115	345	
	10	tplH	1000	50	150	ns
$C_{IN} \rightarrow Sum \text{ out } (L \rightarrow H)$	15		A	35	105	
F	5		11/12 14	130	390	40
Transfer time	10	t _{PHL}	TO TO	50	150	ns
$C_{IN} \rightarrow Sum \ out \ (H \rightarrow L)$	15	(0)	, 2	35	105	
Transfer time	5	. 69	11 - 11	75	225	100
	10	t _{PLH}		35	105	ns
$C_{IN} \rightarrow Cout (L \rightarrow H)$	15		(A) - (A)	25	75	
	5	-9/1, ×	8/, -4//	90	270	
Transfer time	10	t _{PHL}	£ 6).	35	105	ns
$C_{IN} \rightarrow Cout (H \rightarrow L)$	15	9, 40,	115 11	25	75	
nput capacitance		Ci	1 -11/2	2 - 20	7.5	pF

1. Switching Time Measuring Circuit



2. Switching Waveforms



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